

## Small Signal Schottky Diode



### MECHANICAL DATA

**Case:** MiniMELF SOD-80

**Weight:** approx. 31 mg

**Cathode band color:** black

**Packaging codes/options:**

18/10K per 13" reel (8 mm tape), 10K/box

08/2.5K per 7" reel (8 mm tape), 12.5K/box

### FEATURES

- For general purpose applications
- This diode features low turn-on voltage
- The devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- AEC-Q101 qualified
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



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COMPLIANT  
HALOGEN  
**FREE**

### APPLICATIONS

- Applications where a very low forward voltage is required

### PARTS TABLE

| PART    | ORDERING CODE            | INTERNAL CONSTRUCTION | REMARKS       |
|---------|--------------------------|-----------------------|---------------|
| BAS85-M | BAS85-M-18 or BAS85-M-08 | Single diode          | Tape and reel |

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| PARAMETER                                 | TEST CONDITION                         | SYMBOL    | VALUE | UNIT |
|---|--|-----------|-------|------|
| Continuous reverse voltage                |  | $V_R$     | 30    | V    |
| Forward continuous current <sup>(1)</sup> |  | $I_F$     | 200   | mA   |
| Peak forward current <sup>(1)</sup>       |  | $I_{FM}$  | 300   | mA   |
| Surge forward current <sup>(1)</sup>      | $t_p < 1\text{ s}$                     | $I_{FSM}$ | 600   | mA   |
| Power dissipation <sup>(1)</sup>          | $T_{amb} = 65\text{ }^{\circ}\text{C}$ | $P_{tot}$ | 200   | mW   |

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.

### THERMAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| PARAMETER   | TEST CONDITION | SYMBOL     | VALUE         | UNIT               |
|---|----------------|------------|---------------|--------------------|
| Thermal resistance junction to ambient air <sup>(1)</sup> |                | $R_{thJA}$ | 430           | K/W                |
| Junction temperature                                      |                | $T_j$      | 125           | $^{\circ}\text{C}$ |
| Storage temperature range                                 |                | $T_{stg}$  | - 55 to + 150 | $^{\circ}\text{C}$ |

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.

### ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

| PARAMETER                 | TEST CONDITION  | SYMBOL     | MIN. | TYP. | MAX. | UNIT          |
|---------------------------|---|------------|------|------|------|---------------|
| Reverse breakdown voltage | $I_R = 10\text{ }\mu\text{A}$ (pulsed)                            | $V_{(BR)}$ | 30   |      |      | V             |
| Leakage current           | $V_R = 25\text{ V}$   | $I_R$      |      | 0.2  | 2    | $\mu\text{A}$ |
| Forward voltage           | Pulse test $t_p < 300\text{ }\mu\text{s}$ , $I_F = 0.1\text{ mA}$ | $V_F$      |      |      | 240  | mV            |
|                           | Pulse test $t_p < 300\text{ }\mu\text{s}$ , $I_F = 1\text{ mA}$   | $V_F$      |      |      | 320  | mV            |
|                           | Pulse test $t_p < 300\text{ }\mu\text{s}$ , $I_F = 10\text{ mA}$  | $V_F$      |      |      | 400  | mV            |
|                           | Pulse test $t_p < 300\text{ }\mu\text{s}$ , $I_F = 30\text{ mA}$  | $V_F$      |      | 500  |      | mV            |
|                           | Pulse test $t_p < 300\text{ }\mu\text{s}$ , $I_F = 100\text{ mA}$ | $V_F$      |      |      | 800  | mV            |
| Diode capacitance         | $V_R = 1\text{ V}$ , $f = 1\text{ MHz}$                           | $C_D$      |      |      | 10   | pF            |
| Reverse recovery time     | $I_F = 10\text{ mA}$ , $I_R = 10\text{ mA}$ , $i_R = 1\text{ mA}$ | $t_{rr}$   |      |      | 5    | ns            |

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

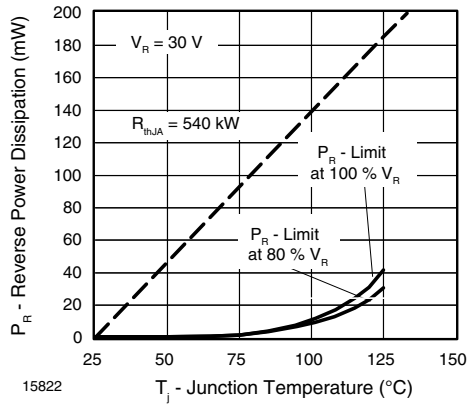


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

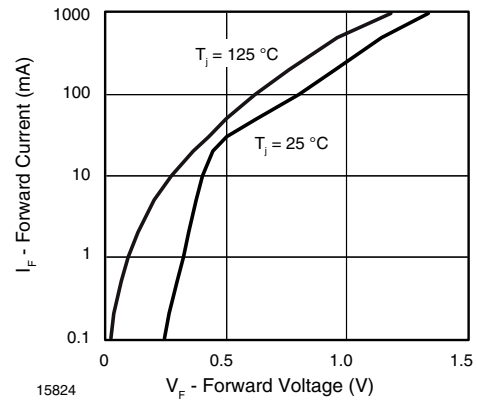


Fig. 3 - Forward Current vs. Forward Voltage

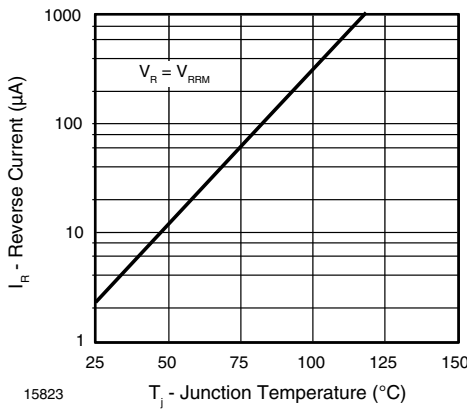


Fig. 2 - Reverse Current vs. Junction Temperature

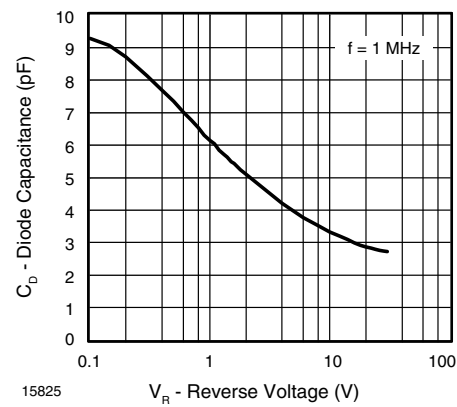
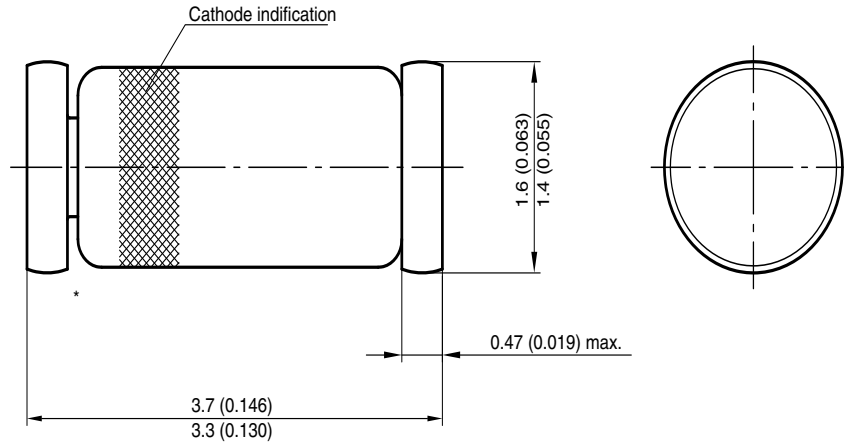
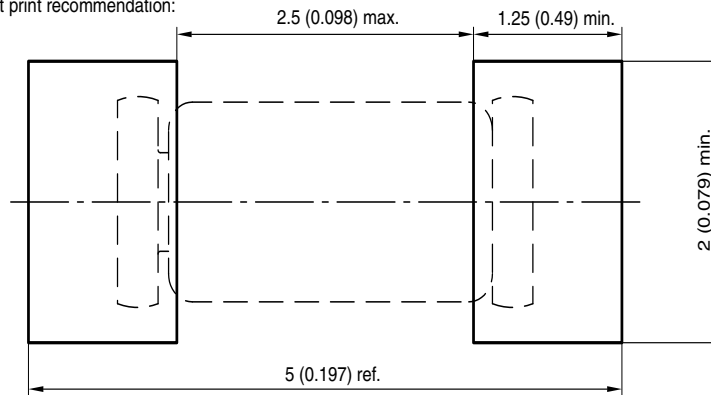


Fig. 4 - Diode Capacitance vs. Reverse Voltage

**PACKAGE DIMENSIONS** in millimeters (inches): **MiniMELF SOD-80**



Foot print recommendation:



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